

# TS321

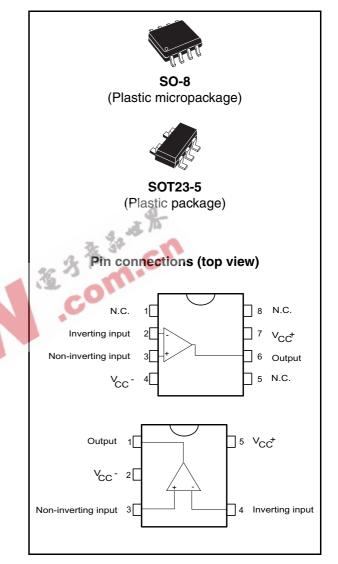
## Low power single operational amplifier

## Features

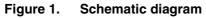
- Large output voltage swing: 0 to 3.5 V min. (V<sub>CC</sub> = 5 V)
- Low supply current: 500 μA
- Low input bias current: 20 nA
- Low input offset voltage: 2 mV max.
- Wide power supply range:
  - Single supply: +3 V to +30 V
  - Dual supplies:  $\pm 1.5$  V to  $\pm 15$  V
- Stable with high capacitive loads

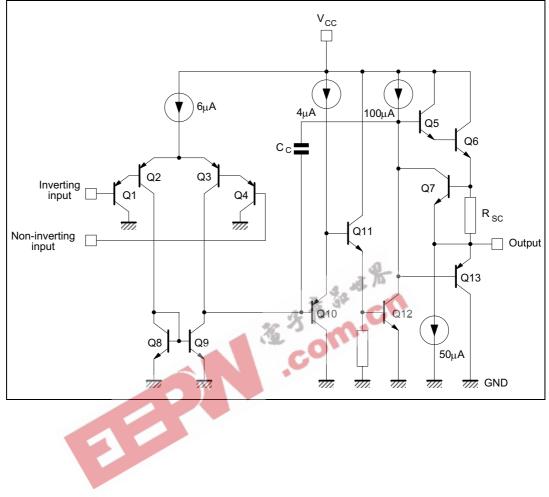
## Description

The TS321 is intended for cost-sensitive applications where space saving is of great importance. This bipolar op-amp offers the benefits of a reduced component size (SOT23-5 package), with specifications that match (or are better than) industry standard devices (like the popular LM358A, LM324, etc.). The TS321 has an input common mode range ( $V_{icm}$ ) that includes ground, and therefore can be employed in single supply applications.



# 1 Circuit schematics





## 2 Absolute maximum ratings and operating conditions

Symbol	Parameter	Value	Unit
$V_{CC}^+$	Supply voltage	±16 to 32	V
V <sub>i</sub>	Input voltage	-0.3 to +32	V
V <sub>id</sub>	Differential input voltage	+32	V
	Output short-circuit duration <sup>(1)</sup>	Infinite	
l <sub>in</sub>	Input current <sup>(2)</sup>	50	mA
T <sub>stg</sub>	Storage temperature range	-65 to +150	°C
Тj	Maximum junction temperature	+150	°C
R <sub>thja</sub>	Thermal resistance junction to ambient <sup>(3)</sup> SOT23-5 SO-8	250 125	°C/W
R <sub>thjc</sub>	Thermal resistance junction to case <sup>(3)</sup> SOT23-5 SO-8	81 40	°C/W
	HBM: human body model <sup>(4)</sup>	300	
	MM: machine model <sup>(5)</sup>	200	
ESD	CDM: charged device model <sup>(6)</sup> Sot23-5 SO-8	1000 1500	V

#### Table 1. Absolute maximum ratings

1. Short-circuits from the output to  $V_{CC}$  can cause excessive heating if  $V_{CC} > 15$  V. The maximum output current is approximately 40 mA independent of the magnitude of  $V_{CC}$ .

2. This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward biased and thereby acting as input diodes clamps. In addition to this diode action, there is also NPN parasitic action on the IC chip. This transistor action can cause the output voltages of the Op-amps to go to the V<sub>CC</sub> voltage level (or to ground for a large overdrive) for the time during which an input is driven negative. This is not destructive and normal output is restored when the input voltage goes back above -0.3V.

3. Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuits on all amplifiers. All values are typical.

4. Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.

- 5. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5  $\Omega$ ). This is done for all couples of connected pin combinations while the other pins are floating.
- 6. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins. The CDM value applies to SO-8 only.



	operating conditions		
Symbol	Parameter	Value	Unit
$V_{CC}^+$	Supply voltage	3 to 30	V
V <sub>icm</sub>	$ \begin{array}{l} \mbox{Common mode input voltage range } (V_{CC}^{+} = 30 \ V) \\ T_{amb} = +25^{\circ}C \\ T_{min} \leq \ T_{amb} \leq T_{max} \end{array} $	0 to V <sub>CC</sub> <sup>+</sup> -1.5 0 to V <sub>CC</sub> <sup>+</sup> -2	V
T <sub>oper</sub>	Operating free-air temperature range	-40 to +125	°C

#### Table 2. Operating conditions





# 3 Electrical characteristics

Table 3.	V <sub>CC</sub> <sup>+</sup> = +5V, V <sub>CC</sub> <sup>-</sup> = (unless otherwise	Ground, $V_o = 1.4V$ , $T_{amb} = +25^{\circ}C$ specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V <sub>io</sub>	Input offset voltage <sup>(1)</sup>	TS321 TS321A $T_{min} \leq T_{amb} \leq T_{max}$ TS321 TS321A		0.5	4 2 5 3	mV
l <sub>io</sub>	Input offset current	$T_{min} \leq T_{amb} \leq T_{max}$		2	30 50	nA
l <sub>ib</sub>	Input bias current <sup>(2)</sup>	$T_{min} \leq T_{amb} \leq T_{max}$		20	150 200	nA
A <sub>vd</sub>	Large signal voltage gain		50 25	100		V/mV
SVR	Supply voltage rejection ratio	$Rs \le 10k\Omega$ , $V_{CC}^+ = 5$ to $30V$	65	110		dB
I <sub>CC</sub>	Supply current, no load	$V_{CC}^{+} = +5V$ $V_{CC}^{+} = +30V$ $T_{min} \le T_{amb} \le T_{max}$ $V_{CC}^{+} = +5V$ $V_{CC}^{+} = +30V$	C	500 600 600	800 900 900 1000	μΑ
CMR	Common mode rejection ratio	$R_{s} \leq 10 k\Omega$	65	85		dB
I <sub>source</sub>	Output current source	$V_{id} = +1V$ $V_{CC}^{+} = +15V, V_{o} = +2V$	20	40		mA
I <sub>sink</sub>	Output sink current	$V_{id} = -1V$ $V_{CC}^{+} = +15V, V_{o} = +2V$ $V_{CC}^{+} = +15V, V_{o} = +0.2V$	10 12	20 50		mA μA
۱ <sub>۵</sub>	Short-circuit to ground	$V_{CC}^{+} = +15V$		40	60	mA
V <sub>OH</sub>	High level output voltage	$\begin{split} & V_{CC}^{+} = +30V,  R_L = 2k\Omega \\ & T_{min} \leq T_{amb} \leq T_{max} \\ & V_{CC}^{+} = +30V,  R_L = 10k\Omega \\ & T_{min} \leq T_{amb} \leq T_{max} \\ & V_{CC}^{+} = +5V,  R_L = 2k\Omega \\ & T_{min} \leq T_{amb} \leq T_{max} \end{split}$	26 25.5 27 26.5 3.5 3	27 28		v
V <sub>OL</sub>	Low level output voltage	$\begin{array}{l} R_{L} = 10 \mathrm{k} \Omega \\ T_{min} \leq \ T_{amb} \leq T_{max} \end{array}$		5	15 20	mV
SR	Slew rate	$V_{CC}^+$ = +15V, $V_i$ = 0.5 to 3V, $R_L$ = 2k $\Omega$ , $C_L$ = 100pF, unity gain		0.4		V/µs
GBP	Gain bandwidth product	$V_{CC}^+$ = 30V, f = 100kHz, $V_{in}$ = 10mV, R <sub>L</sub> = 2k $\Omega$ , C <sub>L</sub> = 100pF		0.8		MHz
φm	Phase margin			60		Degrees

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Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
THD	Total harmonic distortion	$      f = 1 kHz, A_V = 20 dB, R_L = 2 k\Omega, V_o = 2 V_{pp}, \\ C_L = 100 pF, V_{CC}^+ = +30 V $		0.015		%	
en	Equivalent input noise voltage	f = 1kHz, R <sub>s</sub> = 100Ω, V <sub>CC</sub> <sup>+</sup> = +30V		40		$\frac{nV}{\sqrt{Hz}}$	

#### Table 3. $V_{CC}^+ = +5V$ , $V_{CC}^- =$ Ground, $V_o = 1.4V$ , $T_{amb} = +25^{\circ}C$ (unless otherwise specified) (continued)

1.  $V_0 = 1.4 \text{ V}, \text{ R}_s = 0 \ \Omega, 5 \text{ V} < V_{CC}^+ < 30 \text{ V}, 0 < V_{icm} < V_{CC}^+ - 1.5 \text{ V}.$ 

2. The direction of the input current is out of the IC. This current is essentially constant and independent of the state of the output, therefore there is no change in the load on the input lines.



.<u>2V</u>pP

# Figure 2. Current consumption versus temperature



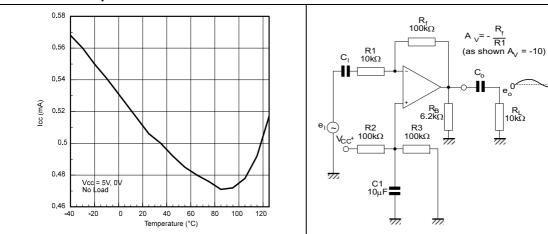




Figure 5. AC coupled non-inverting amplifier

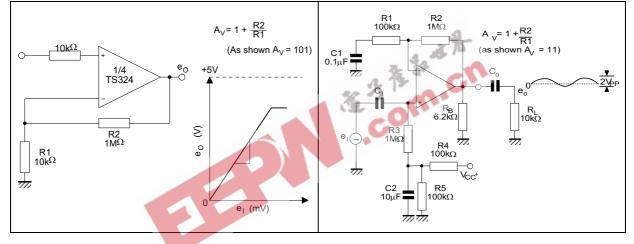
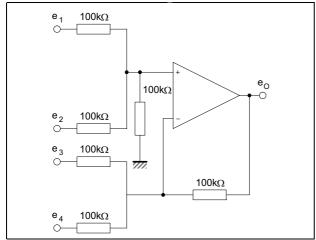


Figure 6. DC summing amplifier



## 4 Macromodel

### 4.1 Important note concerning this macromodel

Please consider the following remarks before using this macromodel.

- All models are a trade-off between accuracy and complexity (i.e. simulation time).
- Macromodels are not a substitute to breadboarding; rather, they confirm the validity of a design approach and help to select surrounding component values.
- A macromodel emulates the nominal performance of a typical device within specified operating conditions (temperature, supply voltage, for example). Thus the macromodel is often not as exhaustive as the datasheet, its purpose is to illustrate the main parameters of the product.

Data derived from macromodels used outside of the specified conditions ( $V_{CC}$ , temperature, for example) or even worse, outside of the device operating conditions ( $V_{CC}$ ,  $V_{icm}$ , for example), is not reliable in any way.

## 4.2 Macromodel code

```
** Standard Linear Ics Macromodels, 1993.
** CONNECTIONS :
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY
.SUBCKT TS321 1 2 3 4 5
*****
.MODEL MDTH D IS=1E-8 KF=3.104131E-15 CJO=10F
* INPUT STAGE
CIP 2 5 1.00000E-12
CIN 1 5 1.000000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 2.600000E+01
RIN 15 16 2.600000E+01
RIS 11 15 2.003862E+02
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 0
VOFN 13 14 DC 0
IPOL 13 5 1.00000E-05
CPS 11 15 3.783376E-09
DINN 17 13 MDTH 400E-12
VIN 17 5 0.000000e+00
DINR 15 18 MDTH 400E-12
VIP 4 18 2.000000E+00
FCP 4 5 VOFP 3.400000E+01
FCN 5 4 VOFN 3.400000E+01
FIBP 2 5 VOFN 2.00000E-03
```



```
FIBN 5 1 VOFP 2.000000E-03
* AMPLIFYING STAGE
FIP 5 19 VOFP 3.600000E+02
FIN 5 19 VOFN 3.600000E+02
RG1 19 5 3.652997E+06
RG2 19 4 3.652997E+06
CC 19 5 6.00000E-09
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 7.500000E+03
VIPM 28 4 1.500000E+02
HONM 21 27 VOUT 7.500000E+03
VINM 5 27 1.500000E+02
EOUT 26 23 19 5 1
VOUT 23 5 0
ROUT 26 3 20
COUT 3 5 1.000000E-12
DOP 19 25 MDTH 400E-12
VOP 4 25 2.242230E+00
DON 24 19 MDTH 400E-12
VON 24 5 7.922301E-01
```



### 4.3

```
Macromodel electrical characteristics
Table 4. V_{CC}^+ = +3V. V_{CC}^-
              V_{CC}^+ = +3V, V_{CC}^- = 0V, R_L, C_L connected to V_{CC}/2, T_{amb} = 25°C
              (unless otherwise specified)
```

Symbol	Conditions	Value	Unit
V <sub>io</sub>		0	mV
A <sub>vd</sub>	$R_L = 2 k\Omega$	100	V/mV
I <sub>CC</sub>	No load, per operator	300	μΑ
V <sub>icm</sub>		0 to +3.5	V
V <sub>OH</sub>	$R_L = 2 k\Omega$	3.5	V
V <sub>OL</sub>	$R_L = 2 k\Omega$	5	mV
I <sub>os</sub>	V <sub>o</sub> = 0 V	40	mA
GBP	$R_L = 2 k\Omega$ , $C_L = 100 pF$	0.8	MHz
SR	$R_L = 2 k\Omega$ , $C_L = 100 pF$	0.4	V/µs
Øm	$R_L = 2 k\Omega$ , $C_L = 100 pF$	60	Degrees



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## 5 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <u>www.st.com</u>.

## 5.1 SOT23-5 package information

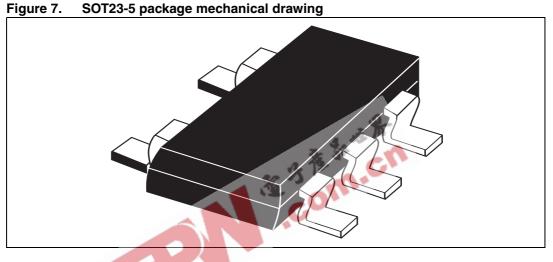
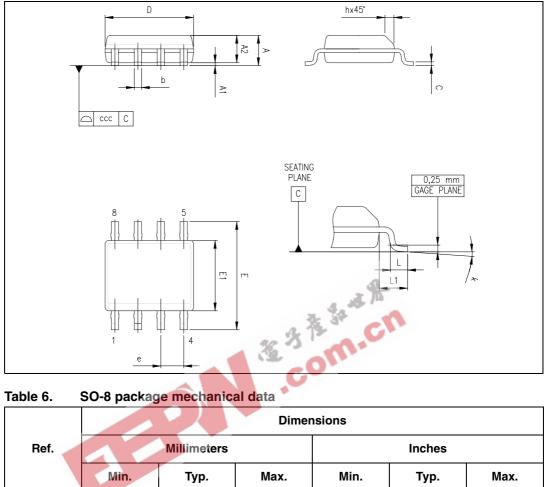


Table 5.	SOT23-5	package	mechanical data
	001200	pachage	meenamear aata

	1-		Dime	nsions		
Ref.		Millimeters			Mils	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.00		5.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
С	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
е		0.95			37.4	
e1		1.9			74.8	
L	0.35		0.55	13.7		21.6

#### 5.2 SO-8 package information

#### Figure 8. SO-8 package mechanical drawing



### Table 6.

			Dime	nsions		
Ref.	~	Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
с	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
Н	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
е		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	<b>1</b> °		8°	1°		<b>8</b> °
CCC			0.10			0.004



# 6 Ordering information

#### Table 7. Order codes

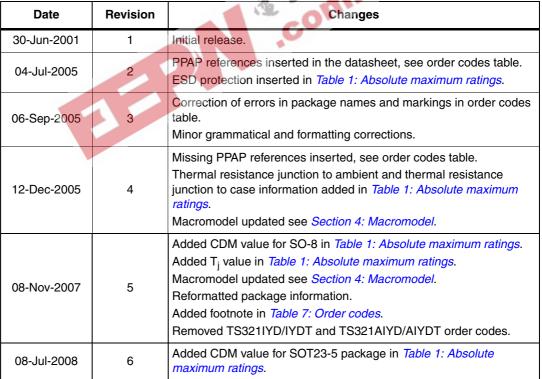
Part number	Temperature range	Package	Packaging	Marking
TS321ILT		SOT23-5L	Tape & reel	K401
TS321AILT		30123-3L	Tape & Teer	K402
TS321ID/IDT		SO-8	Tube or	3211
TS321AID/AIDT	-40°C, +125°C	50-8	tape & reel	321AI
TS321IYLT <sup>(1)</sup>	-	SOT23-5L		K406
TS321AIYLT <sup>(1)</sup>		(Automotive grade level)	Tape & reel	K407

 Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q002 or equivalent are on-going.

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# 7 Revision history

#### Table 8.Document revision history



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